

MRF904

CASE 20-03, STYLE 10
TO-72 (TO-206AF)

HIGH FREQUENCY TRANSISTOR

NPN SILICON



MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CEO}	15	Vdc
Collector-Base Voltage	V_{CBO}	25	Vdc
Emitter-Base Voltage	V_{EBO}	3.0	Vdc
Collector Current — Continuous	I_C	30	mA _{dc}
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	0.2 1.14	Watt mW/ $^\circ\text{C}$
Storage Temperature	T_{stg}	-65 to +200	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted.)

Characteristic	Symbol	Min	Typ	Max	Unit
----------------	--------	-----	-----	-----	------

OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage ($I_C = 1.0$ mA _{dc} , $I_E = 0$)	$V_{(BR)CEO}$	15	—	—	Vdc
Collector-Base Breakdown Voltage ($I_C = 0.1$ mA _{dc} , $I_E = 0$)	$V_{(BR)CBO}$	25	—	—	Vdc
Emitter-Base Breakdown Voltage ($I_E = 0.1$ mA _{dc} , $I_C = 0$)	$V_{(BR)EBO}$	3.0	—	—	Vdc
Collector Cutoff Current ($V_{CB} = 15$ Vdc, $I_E = 0$)	I_{CBO}	—	—	50	nA _{dc}

ON CHARACTERISTICS

DC Current Gain ($I_C = 5.0$ mA _{dc} , $V_{CE} = 5.0$ Vdc)	h_{FE}	30	—	200	—
---	----------	----	---	-----	---

SMALL SIGNAL CHARACTERISTICS

Current-Gain — Bandwidth Product ($I_C = 15$ mA _{dc} , $V_{CE} = 10$ Vdc, $f = 1.0$ GHz)	f_T	—	4.0	—	GHz
Collector-Base Capacitance ($V_{CB} = 10$ Vdc, $I_E = 0$, $f = 1.0$ MHz)	C_{cb}	—	—	1.0	pF
Noise Figure ($I_C = 5.0$ mA _{dc} , $V_{CE} = 6.0$ Vdc, $f = 450$ MHz) ($I_C = 5.0$ mA _{dc} , $V_{CE} = 6.0$ Vdc, $f = 1.0$ GHz)	NF	— —	1.5 2.5	— —	dB

FUNCTIONAL TEST

Maximum Available Power(1) ($I_C = 5.0$ mA _{dc} , $V_{CE} = 6.0$ Vdc, $f = 450$ MHz) ($I_C = 5.0$ mA _{dc} , $V_{CE} = 6.0$ Vdc, $f = 1.0$ GHz)	G_{max}	— —	16 10	— —	dB
--	-----------	--------	----------	--------	----

$$(1) G_{max} = \frac{|S_{21}|^2}{(1 - |S_{11}|^2)(1 - |S_{22}|^2)}$$

FIGURE 1 – NOISE FIGURE versus FREQUENCY

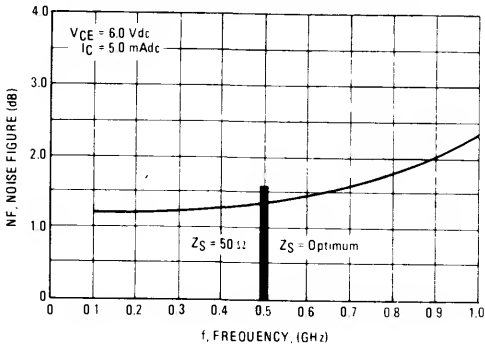


FIGURE 2 – NOISE FIGURE versus COLLECTOR CURRENT

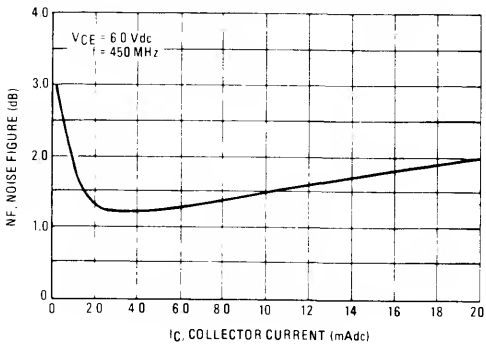


FIGURE 3 – COLLECTOR-BASE CAPACITANCE versus COLLECTOR-BASE VOLTAGE

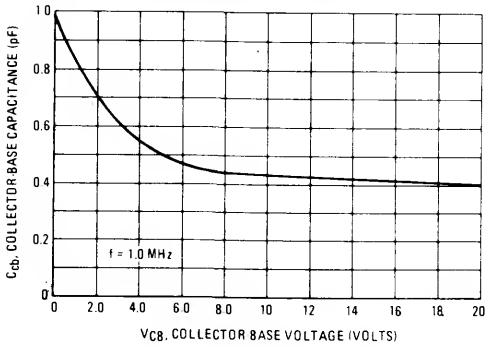


FIGURE 4 – UNILATERALIZED GAIN (G_{max}) versus FREQUENCY

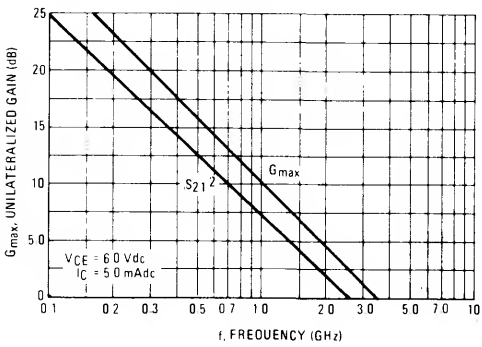


FIGURE 5 – CURRENT-GAIN – BANDWIDTH PRODUCT versus COLLECTOR CURRENT

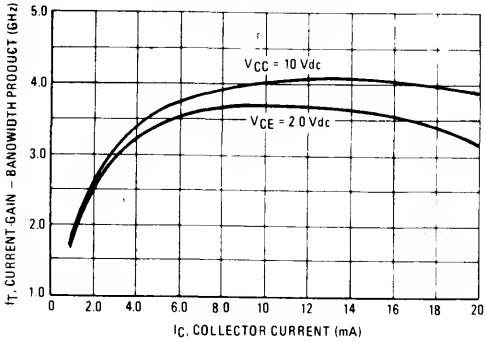


FIGURE 6 – INTERMODULATION DISTORTION versus COLLECTOR CURRENT

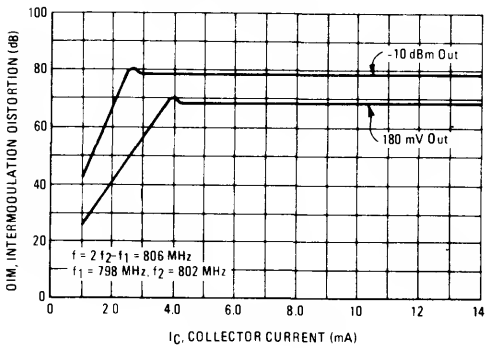


TABLE 1 – S₁₁ PARAMETERS

Frequency (MHz)		100		200		500		800		1000	
V _{CC} (Volts)	I _C (mA)										
		S ₁₁	∠ φ	S ₁₁	∠ φ	S ₁₁	∠ φ	S ₁₁	∠ φ	S ₁₁	∠ φ
1.0	1.0	0.941	-22	0.85	-43	0.57	-91	0.37	-128	0.30	-151
	2.5	0.85	-31	0.67	-57	0.35	-102	0.20	-136	0.14	-157
	5.0	0.69	-44	0.46	-71	0.21	-109	0.10	-144	0.069	-166
	10	0.45	-67	0.28	-94	0.13	-136	0.087	-172	0.075	-145
	15	0.37	-110	0.31	-145	0.26	-170	0.27	-139	0.27	-122
	30	0.71	-178	0.71	-169	0.68	-144	0.68	-121	0.65	-107
3.0	1.0	0.94	-19	0.87	-37	0.61	-80	0.39	-114	0.30	-134
	2.5	0.87	-26	0.71	-47	0.39	-84	0.21	-106	0.15	-115
	5.0	0.74	-34	0.52	-55	0.25	-77	0.13	-82	0.109	-79
	10	0.55	-42	0.35	-58	0.18	-66	0.11	-60	0.105	-55
	15	0.46	-46	0.28	-59	0.15	-64	0.096	-55	0.092	-49
	30	0.28	-95	0.21	-134	0.16	-175	0.17	-135	0.17	-116
6.0	1.0	0.95	-18	0.88	-35	0.63	-76	0.40	-108	0.30	-126
	2.5	0.89	-23	0.74	-43	0.42	-77	0.23	-94	0.17	-100
	5.0	0.77	-31	0.56	-49	0.29	-67	0.18	-69	0.15	-66
	10	0.61	-37	0.40	-50	0.23	-55	0.16	-51	0.16	-50
	15	0.52	-40	0.34	-51	0.20	-52	0.15	-47	0.15	-47
	30	0.36	-55	0.21	-70	0.098	-77	0.037	-59	0.033	-27
10	1.0	0.96	-17	0.89	-33	0.65	-73	0.41	-103	0.31	-121
	2.5	0.89	-22	0.76	-41	0.44	-73	0.25	-88	0.18	-93
	5.0	0.79	-28	0.59	-46	0.32	-63	0.20	-65	0.18	-63
	10	0.64	-34	0.44	-47	0.26	-52	0.19	-49	0.18	-49
	15	0.57	-37	0.38	-48	0.23	-49	0.18	-46	0.17	-46
	30	0.41	-51	0.24	-64	0.12	-67	0.061	-52	0.055	-36

TABLE 2 – S₂₁ PARAMETERS

Frequency (MHz)		100		200		500		800		1000	
V _{CC} (Volts)	I _C (mA)										
		S ₂₁	∠ φ	S ₂₁	∠ φ	S ₂₁	∠ φ	S ₂₁	∠ φ	S ₂₁	∠ φ
1.0	1.0	5.32	156	3.06	137	2.22	97	1.65	70	1.44	56
	2.5	6.79	146	5.57	124	3.15	86	2.14	64	1.81	52
	5.0	10.97	133	7.60	110	3.62	79	2.38	61	2.00	49
	10	13.16	118	8.07	99	3.60	74	2.35	57	1.96	46
	15	9.84	108	5.66	91	2.44	67	1.63	49	1.38	38
	30	1.65	83	0.88	69	0.47	46	0.43	37	0.45	31
3.0	1.0	3.33	159	3.11	142	2.36	103	1.79	76	1.55	62
	2.5	6.89	150	5.85	129	3.48	92	2.38	70	2.00	58
	5.0	11.49	138	8.34	115	4.12	84	2.70	66	2.25	55
	10	15.71	125	9.82	104	4.39	79	2.85	63	2.34	53
	15	16.97	119	10.05	100	4.39	77	2.83	61	2.34	52
	30	12.66	108	7.02	92	2.98	70	1.94	54	1.61	44
6.0	1.0	3.31	160	3.10	144	2.41	106	1.83	79	1.60	65
	2.5	6.80	151	5.85	131	3.60	94	2.46	77	2.07	60
	5.0	11.44	140	8.54	117	4.28	86	2.83	68	2.33	57
	10	15.85	127	10.14	107	4.61	81	2.96	65	2.46	55
	15	17.20	122	10.47	102	4.60	79	2.96	63	2.45	54
	30	16.37	113	9.38	96	4.00	75	2.58	59	2.14	49
10	1.0	3.25	160	3.08	145	2.40	108	1.83	81	1.61	67
	2.5	6.73	152	5.85	132	3.63	96	2.50	74	2.10	62
	5.0	11.19	142	8.49	119	4.34	88	2.85	69	2.37	59
	10	15.59	129	10.16	108	4.66	82	3.00	66	2.47	56
	15	17.04	124	10.49	104	4.65	80	2.99	64	2.47	55
	30	16.18	115	9.38	98	4.03	96	2.60	60	2.14	50

TABLE 3 – S_{12} PARAMETERS

Frequency (MHz)											
V _{CC} (Volts)	I _C (mA)										
		100		200		500		800		1000	
		S ₁₂	∠φ	S ₁₂	∠φ	S ₁₂	∠φ	S ₁₂	∠φ	S ₁₂	∠φ
1.0	1.0	0.054	73	0.097	61	0.159	41	0.184	36	0.194	37
	2.5	0.051	69	0.084	58	0.140	50	0.189	48	0.220	46
	5.0	0.046	65	0.072	60	0.137	58	0.201	53	0.239	50
	10	0.041	64	0.067	64	0.142	62	0.215	56	0.256	51
	15	0.043	61	0.070	63	0.152	62	0.230	55	0.277	50
	30	0.058	50	0.093	58	0.209	57	0.311	46	0.372	39
3.0	1.0	0.039	75	0.072	65	0.123	46	0.143	42	0.151	44
	2.5	0.037	72	0.063	62	0.110	54	0.150	53	0.174	52
	5.0	0.033	70	0.055	64	0.108	62	0.160	58	0.190	55
	10	0.030	70	0.050	68	0.109	67	0.165	61	0.199	57
	15	0.028	70	0.049	70	0.109	68	0.167	62	0.200	57
	30	0.026	68	0.046	70	0.105	69	0.165	64	0.200	61
6.0	1.0	0.032	76	0.060	66	0.106	49	0.123	45	0.131	48
	2.5	0.031	73	0.054	64	0.095	57	0.130	56	0.151	55
	5.0	0.028	71	0.048	66	0.094	64	0.139	61	0.165	58
	10	0.026	71	0.043	69	0.094	68	0.144	63	0.172	59
	15	0.024	71	0.042	71	0.093	69	0.144	64	0.172	60
	30	0.021	71	0.037	72	0.086	71	0.134	67	0.162	63
10	1.0	0.028	77	0.053	68	0.095	50	0.109	47	0.116	50
	2.5	0.027	74	0.048	65	0.085	58	0.116	57	0.134	57
	5.0	0.025	73	0.043	67	0.084	64	0.125	62	0.148	60
	10	0.023	72	0.037	69	0.084	69	0.128	64	0.153	61
	15	0.022	73	0.037	70	0.084	69	0.128	65	0.152	62
	30	0.019	72	0.033	72	0.076	72	0.119	68	0.143	66

TABLE 4 – S_{22} PARAMETERS

Frequency (MHz)											
V _{CC} (Volts)	I _C (mA)										
		100		200		500		800		1000	
		S ₂₂	∠φ	S ₂₂	∠φ	S ₂₂	∠φ	S ₂₂	∠φ	S ₂₂	∠φ
1.0	1.0	0.966	-12	0.893	-23	0.693	-41	0.612	-53	0.594	-59
	2.5	0.901	-18	0.760	-29	0.548	-42	0.498	-51	0.494	-56
	5.0	0.793	-24	0.619	-32	0.456	-39	0.429	-49	0.439	-54
	10	0.635	-29	0.486	-32	0.390	-36	0.377	-47	0.389	-53
	15	0.453	-29	0.364	-29	0.313	-34	0.309	-48	0.321	-14
	30	0.048	-78	0.035	-88	0.032	-135	0.031	-162	0.007	-167
3.0	1.0	0.976	-9.0	0.926	-18	0.770	-35	0.702	-46	0.683	-51
	2.5	0.935	-13	0.828	-23	0.648	-35	0.608	-43	0.608	-48
	5.0	0.853	-18	0.712	-25	0.577	-32	0.555	-41	0.565	-46
	10	0.758	-20	0.629	-23	0.539	-29	0.529	-39	0.544	-44
	15	0.711	-20	0.601	-22	0.533	-27	0.526	-38	0.540	-44
	30	0.631	-15	0.576	-16	0.548	-25	0.546	-38	0.558	-45
6.0	1.0	0.982	-8.0	0.939	-16	0.803	-31	0.742	-42	0.734	-47
	2.5	0.947	-11	0.861	-20	0.699	-31	0.662	-40	0.660	-45
	5.0	0.882	-15	0.759	-21	0.633	-29	0.617	-31	0.627	-43
	10	0.801	-17	0.684	-20	0.607	-26	0.601	-35	0.610	-41
	15	0.769	-17	0.667	-19	0.602	-25	0.601	-35	0.607	-40
	30	0.737	-14	0.672	-15	0.640	-22	0.641	-33	0.655	-40
10	1.0	0.983	-7.0	0.949	-14	0.830	-29	0.774	-39	0.765	-40
	2.5	0.954	-10	0.880	-18	0.733	-29	0.698	-37	0.702	-42
	5.0	0.901	-13	0.793	-19	0.676	-27	0.659	-35	0.668	-41
	10	0.834	-15	0.725	-18	0.646	-24	0.646	-33	0.658	-39
	15	0.802	-15	0.706	-17	0.645	-23	0.648	-33	0.661	-39
	30	0.776	-13	0.712	-14	0.678	-22	0.686	-32	0.699	-38